

REVISIONS

LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
D	Convert to military drawing format. Add vendor CAGE 27014 to case 2. Inactivate case 2 for new design. Inactivate case A for new design. Add vendor CAGE 27014 to case D.	88-01-01	M. A. Frye
E	Update boilerplate to MIL-PRF-38535 requirements. - CFS	01-08-24	Thomas M. Hess
F	Made change to paragraph 3.5. Update boilerplate to MIL-PRF-38535 requirements. - LTG	05-03-17	Thomas M. Hess
G	Add device class V criteria. - jak	06-10-26	Thomas M. Hess
H	Update boilerplate paragraphs to the current MIL-PRF-38535 requirements. - LTG	14-01-28	Thomas M. Hess

CURRENT CAGE CODE 67268

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REV STATUS	REV	H	H	H	H	H	H	H	H	H	H	H	H	H		
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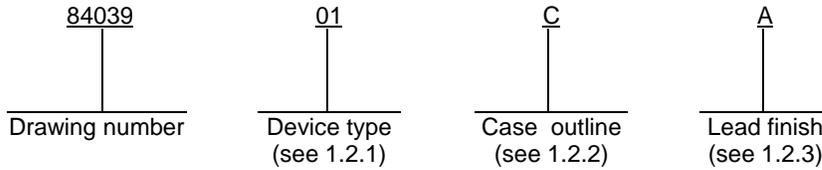
PMIC N/A	PREPARED BY Greg A. Pitz	<p align="center">DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil</p>													
<p align="center">STANDARD MICROCIRCUIT DRAWING</p> <p>THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE</p> <p align="center">AMSC N/A</p>	CHECKED BY D. A. DiGenzo														
	APPROVED BY N. A. Hauck	<p align="center">MICROCIRCUIT, DIGITAL, HIGH-SPEED CMOS, DUAL 4-INPUT NAND GATE, MONOLITHIC SILICON</p>													
	DRAWING APPROVAL DATE 84-05-15														
	REVISION LEVEL H	SIZE A	CAGE CODE 14933	84039											
SHEET 1 OF 12															

1. SCOPE

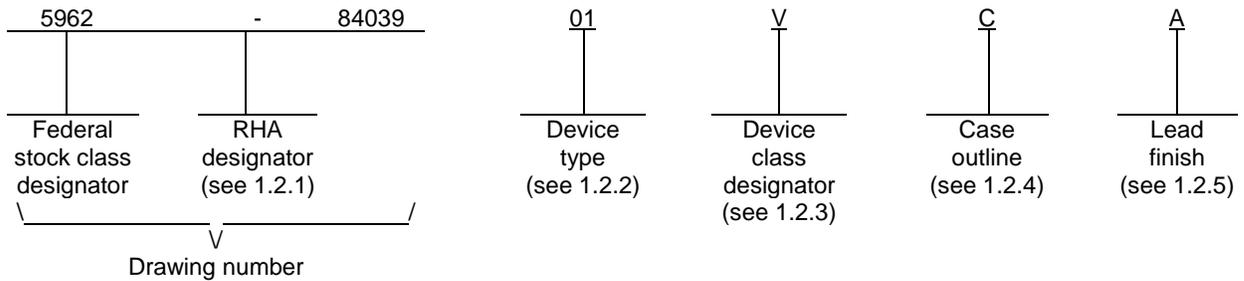
1.1 Scope. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels is reflected in the PIN.

1.2 PIN. The PIN is as shown in the following examples.

For device class M and Q:



For device class V:



1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

<u>Device type</u>	<u>Generic number</u>	<u>Circuit function</u>
01	54HC20	Dual 4-input NAND gate

1.2.3 Device class designator. The device class designator is a single letter identifying the product assurance level as listed below. Since the device class designator has been added after the original issuance of this drawing, device classes M and Q designators will not be included in the PIN and will not be marked on the device.

<u>Device class</u>	<u>Device requirements documentation</u>
M	Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A
Q or V	Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
A	GDFP5-F14 or CDFP6-F14	14	Flat pack
B	GDFP4-F14	14	Flat pack
C	GDIP1-T14 or CDIP2-T14	14	Dual-in-line
D	GDFP1-F14 or CDFP2-F14	14	Flat pack
2	CQCC1-N20	20	Square leadless chip carrier

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 2

1.2.5 Lead finish. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

1.3 Absolute maximum ratings. 1/ 2/ 3/

Supply voltage range (V_{CC}).....	-0.5 V dc to +7.0 V dc
DC input voltage range (V_{IN}).....	-0.5 V dc to $V_{CC} + 0.5$ V dc
DC output voltage range (V_{OUT}).....	-0.5 V dc to $V_{CC} + 0.5$ V dc
Clamp diode current.....	± 20 mA
DC output current (per pin).....	± 25 mA
DC V_{CC} or GND current (per pin).....	± 50 mA
Storage temperature range (T_{STG}).....	-65°C to +150°C
Maximum power dissipation (P_D).....	500 mW <u>4/</u>
Lead temperature (soldering, 10 seconds).....	+260°C
Thermal resistance, junction-to-case (θ_{JC}).....	See MIL-STD-1835
Junction temperature (T_J).....	+175°C <u>5/</u>

1.4 Recommended operating conditions. 2/ 3/

Supply voltage range (V_{DD}).....	+2.0 V dc to +6.0 V dc
Case operating temperature range (T_C).....	-55°C to +125°C
Input rise or fall time:	
$V_{CC} = 2.0$ V.....	0 to 1000 ns
$V_{CC} = 4.5$ V.....	0 to 500 ns
$V_{CC} = 6.0$ V.....	0 to 400 ns

- 1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- 2/ Unless otherwise specified, all voltages are referenced to ground.
- 3/ The limits for the parameters specified herein shall apply over the full specified V_{CC} range and case temperature range of -55°C to +125°C.
- 4/ For $T_C = +100^\circ\text{C}$ to +125°C, derate linearly at 12 mW/°C.
- 5/ Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 3

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
 MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
 MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <https://quicksearch.dla.mil> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094).

2.2 Non-Government publications. The following document(s) form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents cited in the solicitation or contract.

JEDEC – SOLID STATE TECHNOLOGY ASSOCIATION (JEDEC)

JESD7 - Standard for Description of 54/74HCXXXXX and 54/74HCTXXXXX Advanced High-Speed CMOS Devices.

(Copies of these documents are available online at <http://www.jedec.org> or from JEDEC – Solid State Technology Association, 3103 North 10th Street, Suite 240-S Arlington, VA 22201-2107).

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.2 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth table. The truth table shall be as specified on figure 2.

3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3.

3.2.5 Switching waveforms and test circuit. The switching waveforms and test circuit shall be as specified on figure 4.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 4

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DLA Land and Maritime-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.

3.9 Verification and review for device class M. For device class M, DLA Land and Maritime, DLA Land and Maritime's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device class M. Device class M devices covered by this drawing shall be in microcircuit group number 36 (see MIL-PRF-38535, appendix A).

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 5

TABLE I. Electrical performance characteristics.

Test	Symbol	Test conditions -55°C ≤ T _C ≤ +125°C unless otherwise specified 1/	Group A subgroups	Limits		Unit
				Min	Max	
High level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL} I _{OH} = -20 μA	1, 2, 3	V _{CC} = 2.0 V	1.9	V
				V _{CC} = 4.5 V	4.4	
				V _{CC} = 6.0 V	5.9	
	V _{OH}	V _{IN} = V _{IH} or V _{IL} I _{OH} = -4.0 mA	1, 2, 3	V _{CC} = 4.5 V	3.7	V
				V _{CC} = 6.0 V	5.2	
Low level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL} I _{OL} = +20 μA	1, 2, 3	V _{CC} = 2.0 V	0.1	V
				V _{CC} = 4.5 V	0.1	
				V _{CC} = 6.0 V	0.1	
	V _{OL}	V _{IN} = V _{IH} or V _{IL} I _{OL} = +4.0 mA	1, 2, 3	V _{CC} = 4.5 V	0.4	V
				V _{CC} = 6.0 V	0.4	
High level input voltage	V _{IH} 2/		1, 2, 3	V _{CC} = 2.0 V	1.5	V
				V _{CC} = 4.5 V	3.15	
				V _{CC} = 6.0 V	4.2	
Low level input voltage	V _{IL} 2/		1, 2, 3	V _{CC} = 2.0 V	0.3	V
				V _{CC} = 4.5 V	0.9	
				V _{CC} = 6.0 V	1.2	
Input capacitance	C _{IN}	V _{IN} = 0.0 V, T _C = +25°C See 4.4.1c	4		10	pF
Quiescent supply current	I _{CC}	V _{CC} = 6.0 V V _{IN} = V _{CC} or GND	1, 2, 3		40	μA
Input leakage current	I _{IN}	V _{CC} = 6.0 V V _{IN} = V _{CC} or GND	1, 2, 3		±1.0	μA
Functional tests		See 4.4.1d	7, 8			

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 6

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Test conditions -55°C ≤ T _C ≤ +125°C unless otherwise specified <u>1/</u>		Group A subgroups	Limits		Unit
					Min	Max	
Propagation delay time, input to output, high-to-low, low-to-high	t _{PHL} , t _{PLH} <u>3/</u>	T _C = +25°C C _L = 50 pF ±10% See figure 4	V _{CC} =2.0 V	9		110	ns
			V _{CC} =4.5 V			22	
			V _{CC} =6.0 V			19	
		T _C = -55°C and +125°C C _L = 50 pF ±10% See figure 4	V _{CC} =2.0 V	10, 11		165	ns
			V _{CC} =4.5 V			33	
			V _{CC} =6.0 V			28	
Transition time high-to-low, low-to-high	t _{THL} , t _{TLH} <u>4/</u>	T _C = +25°C C _L = 50 pF ±10% See figure 4	V _{CC} =2.0 V	9		75	ns
			V _{CC} =4.5 V			15	
			V _{CC} =6.0 V			13	
		T _C = -55°C and +125°C C _L = 50 pF ±10% See figure 4	V _{CC} =2.0 V	10, 11		110	ns
			V _{CC} =4.5 V			22	
			V _{CC} =6.0 V			19	

1/ For a power supply of 5 V ±10% the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5 V. Thus, the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V respectively. (The V_{IH} value at 5.5 V is 3.85 V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage, and so the 6.0 V values should be used. Power dissipation capacitance (C_{PD}), typically 20 pF, determines the no load dynamic power consumption, P_D = C_{PD} V_{CC}² + I_{CC} V_{CC}, and the no load dynamic current consumption, I_S = C_{PD} V_{CC} f + I_{CC}.

2/ V_{IH} and V_{IL} tests are not required if they are applied as forcing functions for the V_{OH} and V_{OL} tests.

3/ Propagation delay times, when V_{CC} = 2.0 V and 6.0 V shall be guaranteed, if not tested, to the specified parameters.

4/ Transition time (t_{THL}, t_{TLH}), if not tested, shall be guaranteed to the specified parameters.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 7

Device type	01	
Case outlines	A, B, C, and D	2
Terminal number	Terminal symbol	
1	1A	NC
2	1B	1A
3	NC	1B
4	1C	NC
5	1D	NC
6	1Y	1C
7	GND	NC
8	2Y	1D
9	2A	1Y
10	2B	GND
11	NC	NC
12	2C	2Y
13	2D	2A
14	V _{CC}	2B
15		NC
16		NC
17		NC
18		2C
19		2D
20		V _{CC}

NC = No internal connection

FIGURE 1. Terminal connections.

Inputs				Output Y
A	B	C	D	
H	H	H	H	L
L	X	X	X	H
X	L	X	X	H
X	X	L	X	H
X	X	X	L	H

H = High voltage level
L = Low voltage level
X = Irrelevant

FIGURE 2. Truth table.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 8

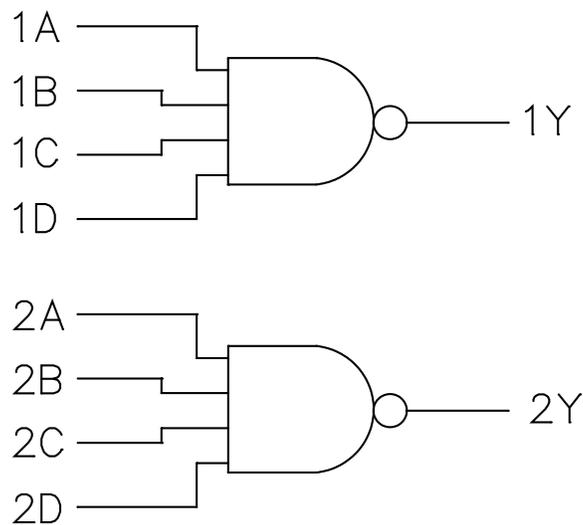
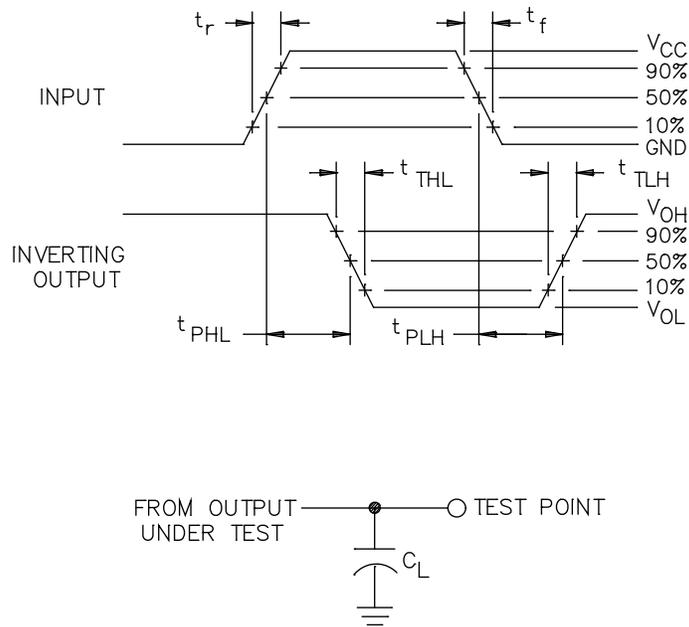


FIGURE 3. Logic diagram.



NOTES:

1. $C_L = 50$ pF minimum or equivalent (includes test jig and probe capacitance).
2. Input signal from pulse generator: $V_{IN} = 0.0$ V to V_{CC} ; $PRR \leq 1$ MHz; $Z_O = 50\Omega$; $t_r = 6.0$ ns; $t_f = 6.0$ ns; t_r and t_f shall be measured from $0.1 V_{CC}$ to $0.9 V_{CC}$ and from $0.9 V_{CC}$ to $0.1 V_{CC}$, respectively; duty cycle = 50 percent.
3. Timing parameters shall be tested at a minimum input frequency of 1 MHz.
4. The outputs are measured one at a time with one transition per measurement.

FIGURE 4. Switching waveforms and test circuit.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 9

4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015.
 - (2) $T_A = +125^{\circ}\text{C}$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5, 6, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C_{IN} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
- d. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 10

TABLE II. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class M	Device class Q	Device class V
Interim electrical parameters (see 4.2)	---	1	1
Final electrical parameters (see 4.2)	<u>1/</u> 1, 2, 9	<u>1/</u> 1, 2, 3, 7, 8, 9, 10, 11	<u>2/</u> 1, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (see 4.4)	1, 2, 3, 4, 7, 9, 10, 11 <u>3/</u>	1, 2, 3, 4, 7, 8, 9, 10, 11	1, 2, 3, 4, 7, 8, 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	<u>4/</u> 1, 2, 3
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)	---	---	---

1/ PDA applies to subgroup 1.

2/ PDA applies to subgroups 1 and 7.

3/ Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.

4/ Delta limits as specified in table III shall be required where specified and the delta limits shall be completed with reference to the zero hour electrical parameters.

TABLE III. Burn-in and operating life test delta parameters (+25°C).

Parameter	Symbol	Delta limits
Quiescent current	I _{CC}	±120 nA
Input current low level	I _{IL}	±20 nA
Input current high level	I _{IH}	±20 nA
Output voltage low level (I _{OL} = 4 mA, V _{CC} = 4.5 V)	V _{OL}	±0.026 V
Output voltage high level (I _{OH} = -4 mA, V _{CC} = 4.5 V)	V _{OH}	±0.20 V

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
- b. T_A = +125°C, minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.2.1 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 11

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

- a. End-point electrical parameters shall be as specified in table II herein.
- b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^{\circ}\text{C} \pm 5^{\circ}\text{C}$, after exposure, to the subgroups specified in table II herein.

4.5 Methods of inspection. Methods of inspection shall be specified as follows:

4.5.1 Voltage and current. Unless otherwise specified, all voltages given are referenced to the microcircuit GND terminal. Currents given are conventional current and positive when flowing into the referenced terminal.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime-VA, telephone (614) 692-8108.

6.4 Comments. Comments on this drawing should be directed to DLA Land and Maritime-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in MIL-HDBK-103 and QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DLA Land and Maritime-VA and have agreed to this drawing.

6.6.2 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DLA Land and Maritime-VA.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		84039
		REVISION LEVEL H	SHEET 12

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 14-01-28

Approved sources of supply for SMD 84039 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at <http://www.landandmaritime.dla.mil/Programs/Smcr/>.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>
8403901AA <u>3/</u>	<u>4/</u>	MM54HC20W/883
8403901BA <u>3/</u>	<u>4/</u>	SNJ54HC20WA
8403901CA	01295	SNJ54HC20J
		CD54HC20F3A
8403901DA	01295	SNJ54HC20W
84039012A	01295	SNJ54HC20FK
5962-8403901VCA	01295	SNV54HC20J
5962-8403901VDA	01295	SNV54HC20W

1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.

2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

3/ Inactive for new design.

4/ Not available from an approved source of supply.

Vendor CAGE
number

01295

Vendor name
and address

Texas Instruments Inc.
Semiconductor Group
8505 Forest Ln.
P.O. Box 660199
Dallas, TX 75243
Point of contact: U.S. Highway 75 South
P.O. Box 84, M/S 853
Sherman, TX 75090-9493

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